Preliminary TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

T C 7 M B 3 2 5 1 F K

1-of-8 FET Multiplexer/Demultiplexer

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The TC7MB3251FK is high-speed CMOS 1-8 multiplexer/demultiplexer. The low on resistance of the switch allows connections to be made with minimal propagation delay time.

This device is 1 to 8 multiplexer/demultiplexer controlled by the combination of select inputs (S0, S1, S2) and output enable (\overline{OE}). The A inputs is connected to the corresponded B1~B8 outputs determined by the combination both the select inputs (S0, S1, S2) and output enable (\overline{OE}). When the output enable (\overline{OE}) input is held "H" level, the switches are open with regardless the state of select inputs and a high-impedance state exists between the switches.

All inputs are equipped with protection circuits against static discharge.

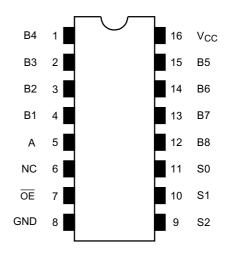
Features

- Operating voltage: VCC = 4.5~5.5 V
- High speed: $t_{pd} = 0.25$ ns (max)
- Low on resistance: $R_{ON} = 5 \Omega$ (typ.)
- ESD performance: Machine model > $\pm 200 \text{ V}$ Human body model > $\pm 2000 \text{ V}$
- Compatible with TTL outputs (control inputs)
- Package: VSSOP (US16)
- Pin compatible with the 74xx251 type. Functionally equivalent to (FST/CBT) 3251.

Pin Assignment (top view)

Weight: 0.02 g (typ.)

VSSOP16-P-0030-0.50



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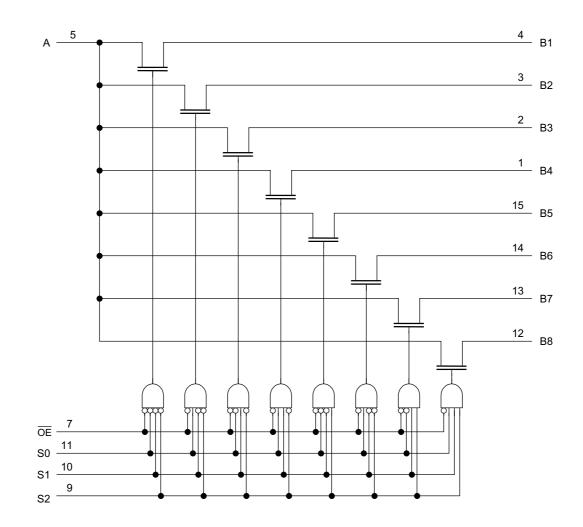
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Truth Table

	Inp	Function		
ŌĒ	S2	S1	S0	1 unction
L	L	L	L	A port = B1 port
L	L	L	Н	A port = B2 port
L	L	Н	L	A port = B3 port
L	L	Н	Н	A port = B4 port
L	Н	L	L	A port = B5 port
L	н	L	Н	A port = B6 port
L	н	н	L	A port = B7 port
L	Н	Н	Н	A port = B8 port
н	х	х	Х	Disconnect

System Diagram



Maximum Ratings

Characteristics	Symbol	Rating	Unit
Power supply range	V _{CC}	-0.5~7.0	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC switch voltage	VS	-0.5~7.0	V
Input diode current	I _{IK}	-50	mA
Continuous channel current	I _S	128	mA
Power dissipation	PD	180	mW
DC V _{CC} /GND current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65~150	°C

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	4.5~5.5	V	
Input voltage (OE , S)	V _{IN}	0~5.5	V	
Switch voltage	VS	0~5.5	V	
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dv	0~10	ns/V	

Electrical Characteristics

DC Characteristics ($Ta = -40 \sim 85^{\circ}C$)

Characteristics		Symbol	Test Condition		Min	Тур.	Max	Unit	
		Cymbol			V _{CC} (V)	IVIIII	(Note1)	Max	Offic
Input voltage	"H" level	VIH	—		4.5~5.5	2.0	_	_	V
input voltage	"L" level	VIL	_		4.5~5.5		_	0.8	v
Input leakage current ($\overline{\text{OE}}$, S)		I _{IN}	$V_{IN} = 0 \sim 5.5 V$		5.5	_	_	±1.0	μA
Off-state leakage current		1	A, B = $0 \sim 5.5 \text{ V}$, $\overline{\text{OE}} =$	Vaa	5.5			±1.0	
(switch off)		I _{SZ}	A, B = 0.3, V, OE = VCC		5.5		_	±1.0	μA
ON resistance (Note2)			V _{IS} = 0 V	I _{IS} = 64 mA	4.5		5	7	Ω
		R _{ON}	VIS - 0 V	I _{IS} = 30 mA	4.5		5	7	
			$V_{IS} = 2.4 \text{ V}, \ I_{IS} = 15 \text{ m}.$	A	4.5	_	10	15	
Increase in I _{CC} per input		ICC	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$		5.5	_	_	10	μA
increase in ICC per input		ΔI_{CC}	V _{IN} = 3.4 V (one input)		5.5	_	_	2.5	mA

Note1: Typical values are at $V_{CC} = 5 V$, Ta = 25°C.

Note2: Measured by the voltage drop between A and B pins at the indicated current through the switch. ON resistance is determined by the lower of the voltages on the two (A or B) pins.

AC Characteristics (Ta = -40~85°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time (bus to bus)	t _{pLH} t _{pHL}	Figure 1, Figure 2 (Note3)	4.5	_	0.25	ns
Propagation delay time (S to bus)	t _{pLH} t _{pHL}	Figure 1, Figure 2	4.5	_	TBD	ns
Output enable time (OE to bus)	t _{pZL} t _{pZH}	Figure 1, Figure 3	4.5	_	TBD	ns
Output enable time (S to bus)	t _{pZL} t _{pZH}	Figure 1, Figure 3	4.5	_	TBD	ns
Output disable time (OE to bus)	t _{pLZ} t _{pHZ}	Figure 1, Figure 3	4.5	_	TBD	ns
Output disable time (S to bus)	t _{pLZ} t _{pHZ}	Figure 1, Figure 3	4.5	_	TBD	ns

Note3: This parameter is guaranteed by design but is not tested. The bus switch contributes no propagation delay other than the RC delay of the typical on resistance of the switch and the 50 pF load capacitance, when driven by an ideal voltage the source (zero output impedance).

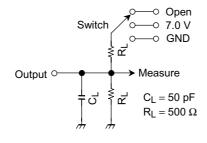
Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Control pin input capacitance ($\overline{\text{OE}}$, S)	C _{IN}	(Note4)	5.0	3	pF
Switch terminal capacitance (B1~8)	C _{I/O}	$\overline{OE} = V_{CC}$ (Note4)	5.0	10	pF
Switch terminal capacitance (A)	C _{I/O}	$\overline{OE} = V_{CC}$ (Note4)	5.0	59	pF

Note4: This parameter is guaranteed by design.

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AC Test Circuit



Parameter	Switch		
t _{pLH} , t _{pHL}	Open		
t _{pLZ} , t _{pZL}	7.0 V		
t _{pHZ} , t _{pZH}	Open		



AC Waveform

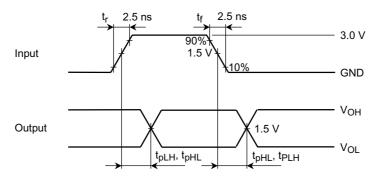
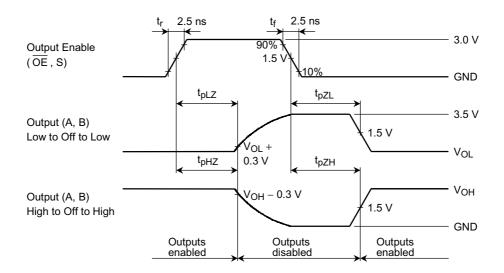
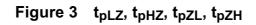


Figure 2 t_{pLH}, t_{pHL}

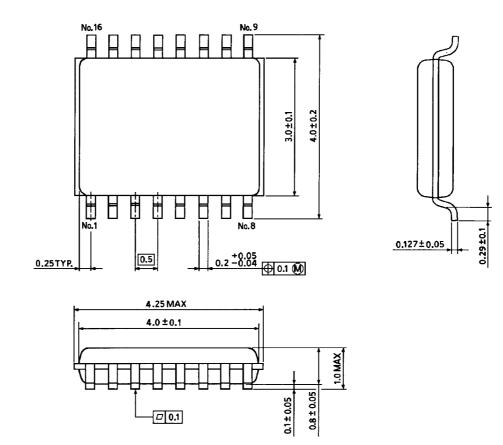




Package Dimensions

VSSOP16-P-0030-0.50

Unit : mm



Weight: 0.02 g (typ.)